Near Ultraviolet (NUV) SiPMs

Silicon photomultipliers (SiPMs) from First Sensor are innovative solid-state silicon detectors with single photon sensitivity. SiPMs are a valid alternative to photomultiplier tubes. The main benefits of these detectors are high gain, extremely good timing performance and low operating voltage. They are insensitive to magnetic field and have a high integration level. The detectors are optimized for Near Ultraviolet (NUV) light detection.



Features

- NUV light detection from 350 to 900 nm (peak efficiency at 420 nm)
- Afterpulsing probability <4 %
- Dark Count Rate <100 kHz/mm²
- Superior breakdown voltage uniformity
- Excellent temperature stability
- Detection of extremely faint light
- Very high gain (10°)
- Extremely good timing performance
- Insensitive to magnetic fields
- Not damaged by ambient light
- Small and compact
- Nickel free Chip Scale Package (CSP)

Applications

- High energy physics
- Medical imaging
- Nuclear medicine
- Homeland security
- Analytical instruments

Certificates

- RoHS compliant (2011/65/EU)

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Absolute maximum ratings (1)

Parameter	Min.	Max.	Unit
Operating temperature (T _A)	-25	+40	°C
Storage temperature (T _s)	-40	+60	°C
Lead temperature (solder) 5 s (T _{sol})		+250	°C
Voltage working range (MVW)		Breakdown voltage +6	V

Typical characteristics

Parameter	Product					
	SiPM-NUV1S-SMD	SiPM-NUV1C-SMD	SiPM-NUV3S-SMD	SiPM-NUV4S-SMD		
Effective active area	(1×1) mm ²	1.13 mm ²	(3×3) mm ²	(4×4) mm ²		
Cell count	625	673	5520	9340		
Cell size (pitch)	40 μm × 40 μm					
Cell fill-factor	60 %					
Quenching resistance	800 kΩ					
Cell capacitance	90 fF					
Recharge time constant	70 ns					
Spectral response range	350 900 nm					
Peak sensitivity wavelength	420 nm					
Photon detection efficiency ⁽²⁾	43 %					
Breakdown voltage (BV)	typ. 26 V, min. 24 V, max. 28 V					
BV standard deviation ⁽³⁾	50 mV					
Recommended overvoltage range (OV) ⁽⁴⁾	min: 2 V, max: 6 V					
Dark count rate ⁽⁵⁾	<50 kHz/mm² @ 2 V OV, <100 kHz/mm² @ 6 V OV					
Gain ⁽⁶⁾	3.6×10 ⁶					
Breakdown voltage temperature coefficient	26 mV/°C					
Refractive index of epoxy resin ⁽⁷⁾	1.5115 (@ 589 nm, 23 °C, uncured)					
Spectral transmission of epoxy resin ⁽⁷⁾	>97% @ 1000 1600 nm ; >99% @ 400 1000 nm					

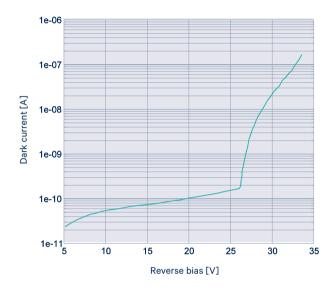
Specification notes

- (1) Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.
- (2) Measured at peak sensitivity wavelength $(\lambda = \lambda_p)$ at +6 V overvoltage (not including afterpulse and crosstalk).
- (3) BV of SiPMs belonging to a same production lot are within 200 mV (±2 σ) from mean BV value.
- (4) Operating voltage (SiPM bias) is BV+OV, to be applied in reverse mode, i.e. $V_{\rm AK}$ <0 (see "Pins Function" section).
- (5) 0.5 p.e. threshold level at 20 °C (primary dark count rate; not including afterpulse).
- (6) Measured at 20 °C at +6 V overvoltage.
- (7) To be used as a guide only, not as a specification. Reported data is not guaranteed.

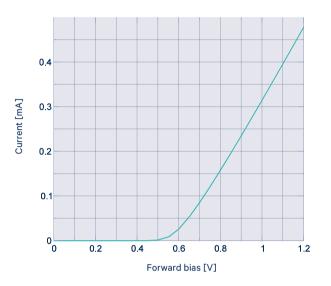
Near Ultraviolet (NUV) SiPMs

Device characteristics ^(8, 9)

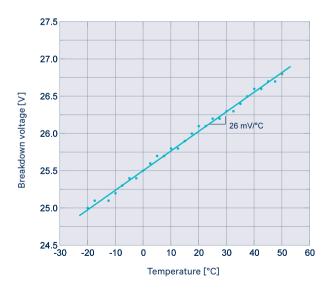
Typical reverse IV curve (SiPM-NUV1S-SMD)



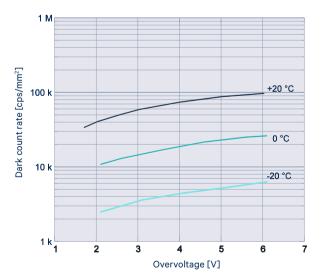
Typical forward IV curve (SiPM-NUV1S-SMD)



Breakdown voltage temperature dependence



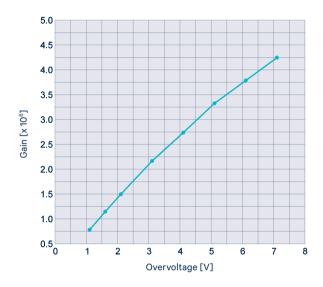
Dark count rate as fct of overvoltage and temperature



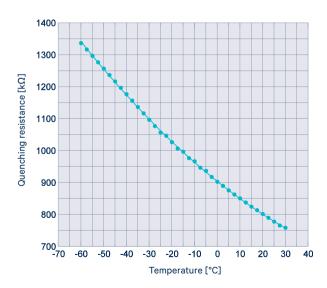
Near Ultraviolet (NUV) SiPMs

Device characteristics (cont.) (8,9)

Gain as fct of overvoltage



Temperature dependence of poly-silicon quenching resistance



Relative variation of gain with temperature as fct of overvoltage

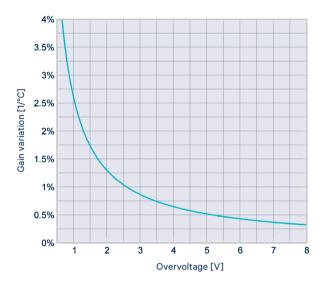
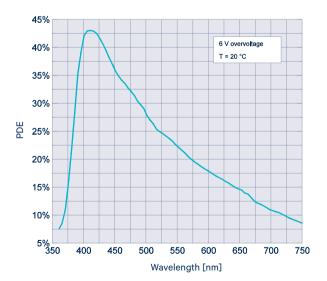


Photo detection efficiency (PDE) as fct of wavelength (crosstalk and afterpulse not included)

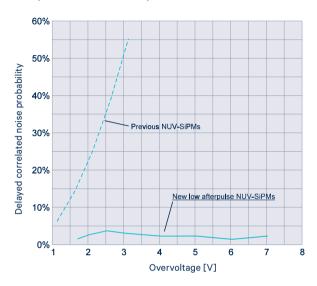


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Device characteristics (cont.) (8,9)

Delayed correlated noise probability

(delayed crosstalk and afterpulse)

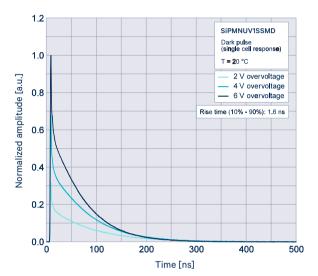


Specification notes

- (8) T₄ = 20 °C
- (9) Refer to the data accompanying each shipped product for more detailed information.

Pulse shape at different overvoltage

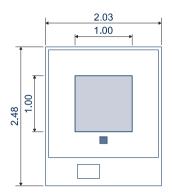
(recharge time constant is 70 ns)

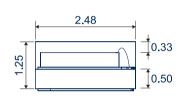


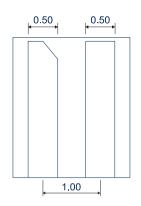
Near Ultraviolet (NUV) SiPMs

Physical dimensions

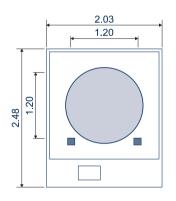
SiPM-NUV1S-SMD



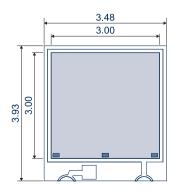




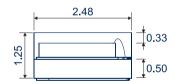
SiPM-NUV1C-SMD

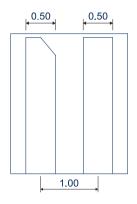


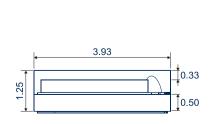
SiPM-NUV3S-SMD

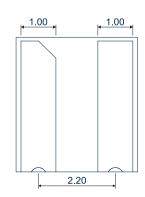


Material: Black FR4, transparent epoxy layer







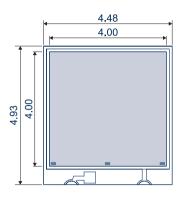


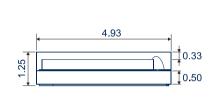
dimensions in mm, mechanical tolerance ± 0.15 mm unless otherwise noted

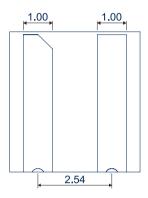
Near Ultraviolet (NUV) SiPMs

Physical dimensions

SiPM-NUV4S-SMD



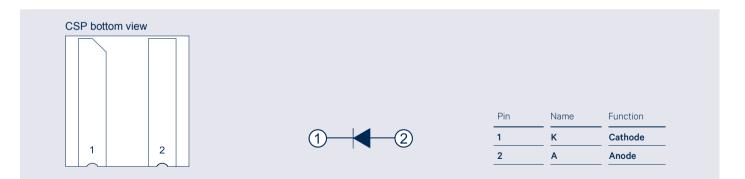




Material: Black FR4, transparent epoxy layer

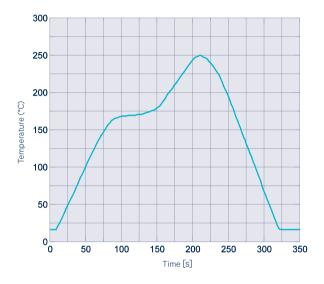
dimensions in mm, mechanical tolerance ±0.15 mm unless otherwise noted

Electrical connection



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Reflow soldering profile (10)



Specification notes

(10) The reflow soldering must be performed within 24 hours once the device has been removed from package and stored in a 25 °C and <60 % RH ambient conditions. The reflow soldering profile is recommended for Pb-free solder such as Tin-Silver-Copper (SAC). The peak temperature must not exceed 250 °C.

Ordering information

Order #	Series	Range	Active area		Housing	
5000076			1S	(1x1) mm ² square		
5000077	SiPM-	NUV [Near Ultraviolet]	1C	Ø 1.2 mm circular		
5000078			3S	(3x3) mm ² square		
5000079			4S	(4x4) mm ² square		

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